



### **60V N-Channel Enhancement Mode MOSFET**

Voltage

60 V

Current

250mA

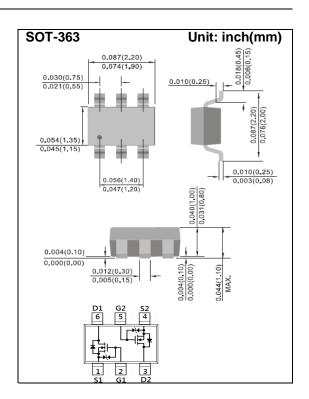
#### **Features**

- RDS(ON), VGS@10V, ID@300mA<5Ω
- RDS(ON), VGS@5V, ID@50mA<7.5Ω</li>
- Advanced Trench Process Technology
- ESD Protected
- Specially Designed for Relay driver, Speed line drive, etc.
- Lead free in compliance with EU RoHS 2011/65/EU directive.
- Green molding compound as per IEC61249 Std. (Halogen Free)

#### **Mechanical Data**

Case: SOT-363 Package

Terminals: Solderable per MIL-STD-750, Method 2026



### Maximum Ratings and Thermal Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		V <sub>DS</sub>	60	V
Gate-Source Voltage		$V_{GS}$	<u>+</u> 20	V
Continuous Drain Current		I <sub>D</sub>	250	mA
Pulsed Drain Current		I <sub>DM</sub>	1000	mA
Power Dissipation	T <sub>A</sub> =25°C	P <sub>D</sub>	350	mW
	Derate above 25°C		2.8	mW/°C
Operating Junction and Storage Temperature Range		$T_J, T_{STG}$	-55~150	°C
Typical Thermal Resistance				
- Junction to Ambient (Note 3)		$R_{\theta JA}$	357	°C/W





# **Electrical Characteristics** (T<sub>A</sub>=25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS	
Static							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V,I <sub>D</sub> =250uA	60	-	-	V	
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$ , $I_{D}=250uA$	2.0	2.49	3.0	V	
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> =10V,I <sub>D</sub> =300mA	-	2.0	5	Ω	
		V <sub>GS</sub> =5V,I <sub>D</sub> =50mA	-	3.6	7.5		
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =60V,V <sub>GS</sub> =0V	-	-	1	uA	
Gate-Source Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> = <u>+</u> 20V,V <sub>DS</sub> =0V	-	-	<u>+</u> 0.5	uA	
Dynamic (Note 4)							
Total Gate Charge	$Q_g$	$V_{DS}$ =10V, $I_{D}$ =300mA, $V_{GS}$ =4.5V (Note 1,2)	-	1.3	-	nC	
Gate-Source Charge	$Q_{gs}$		-	0.6	-		
Gate-Drain Charge	$Q_{gd}$		-	0.2	-		
Input Capacitance	Ciss	V <sub>DS</sub> =25V, V <sub>GS</sub> =0V, f=1.0MHZ	-	22	-	pF ns	
Output Capacitance	Coss		-	12	-		
Reverse Transfer Capacitance	Crss		-	1.7	-		
Turn-On Delay Time	td <sub>(on)</sub>	$V_{DD}{=}10V, I_{D}{=}300mA,$ $V_{GS}{=}10V,$ $R_{G}{=}10\Omega^{(Note~1,2)}$	-	2.9	-		
Turn-On Rise Time	tr		-	1.8	-		
Turn-Off Delay Time	td <sub>(off)</sub>		-	5.6	-		
Turn-Off Fall Time	tf		-	1.9	-		
Drain-Source Diode	1	<del>-</del>					
Maximum Continuous Drain-Source	I <sub>S</sub>	_	-	-	300	mA	
Diode Forward Current	IS						
Diode Forward Voltage	V <sub>SD</sub>	I <sub>S</sub> =300mA, V <sub>GS</sub> =0V	-	0.92	1.5	V	

### NOTES:

- 1. Pulse width<a></a>300us, Duty cycle<a></a>2%
- 2. Essentially independent of operating temperature typical characteristics.
- 3. R<sub>OJA</sub> is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. mounted on a 1 inch square pad of copper
- 4. Guaranteed by design, not subject to production testing





#### **TYPICAL CHARACTERISTIC CURVES**

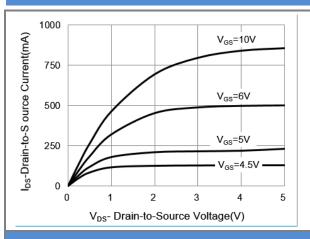
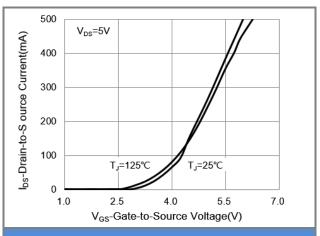


Fig.1 On-Region Characteristics



**Fig.2 Transfer Characteristics** 

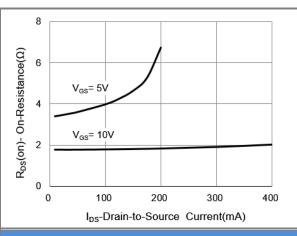


Fig.3 On-Resistance vs. Drain Current

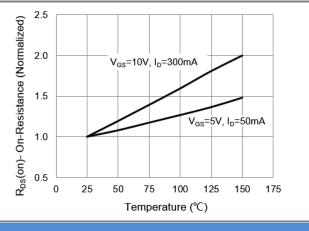


Fig.4 On-Resistance vs. Junction temperature

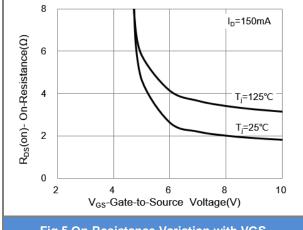
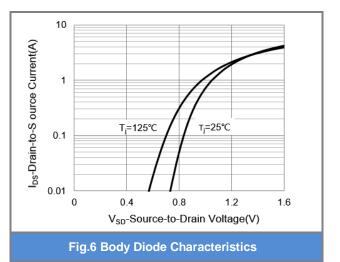


Fig.5 On-Resistance Variation with VGS.







#### **TYPICAL CHARACTERISTIC CURVES**

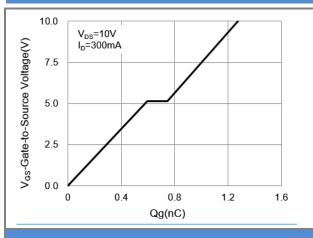
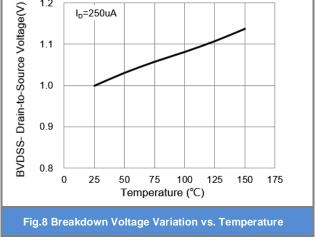


Fig.7 Gate-Charge Characteristics



1.2

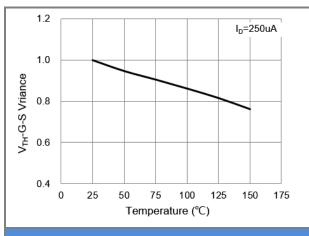


Fig.9 Threshold Voltage Variation with Temperature.

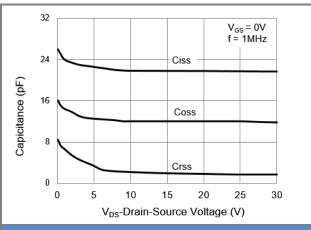


Fig.10 Capacitance vs. Drain-Source Voltage.

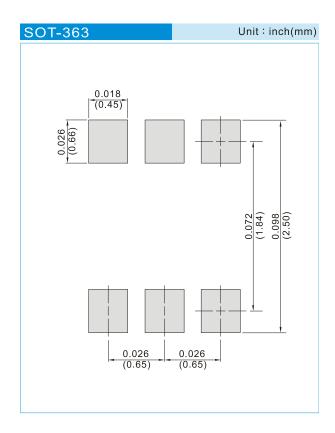




### PART NO PACKING CODE VERSION

PART NO PACKING CODE	Package Type	Packing Type	Marking	Version
PJT7002H_R1_00001	SOT-363	3K pcs / 7" reel	T2H	Halogen free
PJT7002H_R2_00001	SOT-363	10K pcs / 13" reel	T2H	Halogen free

### **MOUNTING PAD LAYOUT**







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